## NSN 5962-01-155-4176

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-155-4176

Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inches an	ld 0.310 inches
Body Height:	
Between 0.140 inches an	ld 0.185 inches
Maximum Power Dissip	ation Rating:
739.0 milliwatts	
Operating Tempurature	Range:
-55.0/+125.0 degrees cel	sius
Storage Tempurature R	ange:
-65.0/+150.0 degrees cel	sius
Features Provided:	
Hermetically sealed and	monolithic and positive outputs and schottky and programmable and programmed and bipolar and w/enable and
w/decoded output and w/	buffered output
Inclosure Material:	
Ceramic and glass	
Inclosure Configuration	1:
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	;
Input Circuit Pattern:	
10 input	
Case Outline Source Ar	nd Designator:
D-2 mil-m-38510	
Terminal Surface Treat	nent:
Solder	
Voltage Rating And Typ	e Per Characteristic:
5.5 volts power source	
Time Rating Per Chacte	ristic:
75.00 nanoseconds prop	pagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Test Data Document:	
81349-mil-m-38510 spec	ification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes comme	ercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and perfor	mance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Oua	

## Terminal Type And Quantity:

16 printed circuit

Shalf Life

## Specification Data:

81349-mil-m-38510/203 government specification

## NSN 5962-01-155-4176

Memory Microcircuit - Page 2 of 2

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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